

WNSC201200W

Silicon Carbide Diode

Rev.01 - 22 April 2019

Product data sheet

1. General description

Silicon Carbide Schottky diode in a TO247-2L plastic package, designed for high frequency switched-mode power supplies.



2. Features and benefits

- Highly stable switching performance
- High forward surge capability I_{FSM}
- Extremely fast reverse recovery time
- Superior in efficiency to Silicon Diode alternatives
- Reduced losses in associated MOSFET
- Reduced EMI
- Reduced cooling requirements
- RoHS compliant
- High junction operating temperature capability (T_{j(max)} = 175 °C)

3. Applications

- Power factor correction
- Telecom / Server SMPS
- UPS
- PV inverter
- PC Silverbox
- LED / OLED TV
- Motor Drives

4. Quick reference data

Table 1. Quick reference data

Symbol	Parameter	Conditions		Va	lues		Unit
		Conditions		V C	liues		
Absolute	maximum rating						
V_{RRM}	repetitive peak reverse voltage		1200				
$I_{F(AV)}$	average forward current	δ = 0.5 ; square-wave pulse; T _{mb} ≤ 131 °C; Fig. 1; Fig. 2; Fig. 3; Fig. 4	20				A
T _j	junction temperature			175			
Symbol	Parameter	Conditions	Min Typ Max				Unit
Static ch	aracteristics						
V _F	forward voltage	I _F = 20 A; T _j = 25 °C; <u>Fig. 6</u>		-	1.4	1.6	V
		I _F = 20 A; T _j = 150 °C; <u>Fig. 6</u>		-	1.85	2.3	V
		I _F = 20 A; T _j = 175 °C; <u>Fig. 6</u>		-	2	2.6	V
Dynamic	characteristics	·			,		
Q _r	recovered charge	$I_F = 20 \text{ A}; V_R = 400 \text{ V}; dI_F/dt = 500 \text{ A}/\mu\text{s};$ $T_j = 25 \text{ °C}; Fig. 8$		-	52	-	nC

5. Pinning information

Table 2.	Pinning infor	mation		
Pin	Symbol	Description	Simplified outline	Graphic symbol
1	K	cathode		K — A 001aaa020
2	А	anode		001888020
mb	К	mounting base; connected to cathode	С О О П	

6. Ordering information

Table 3. Ordering information												
Type number	Package name	Orderable part number	Packing method	Small packing quantity		Package issue date						
WNSC201200W	TO247-2L	WNSC201200WQ	Tube	30	TO247L-2L	28-Aug-2018						

7. Marking

Table 4. Marking codes								
	Type number	Marking codes						
	WNSC201200W	WNSC201200W						

8. Limiting values

Table 5. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions	Values	Unit	
V_{RRM}	repetitive peak reverse voltage		1200	V	
V _{RWM}	crest working reverse voltage		1200	V	
V _R	reverse voltage	DC	1200	V	
$I_{F(AV)}$	average forward current	δ = 0.5 ; square-wave pulse; T _{mb} ≤ 131 °C; Fig. 1; Fig. 2; Fig. 3; Fig. 4	20	A	
I _{FRM}	repetitive peak forward current	δ = 0.5; t _p = 25 μs; T _{mb} ≤ 131 °C; square-wave pulse	40	A	
I _{FSM}	non-repetitive peak				
	forward current	t_p = 10 µs; $T_{j(init)}$ = 25 °C; sine-wave pulse	1440	А	
T _{stg}	storage temperature		-55 to 175	°C	
Tj	junction temperature		175	°C	

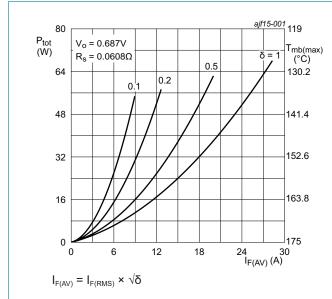
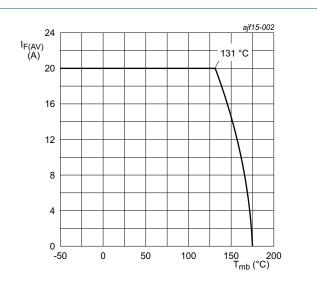
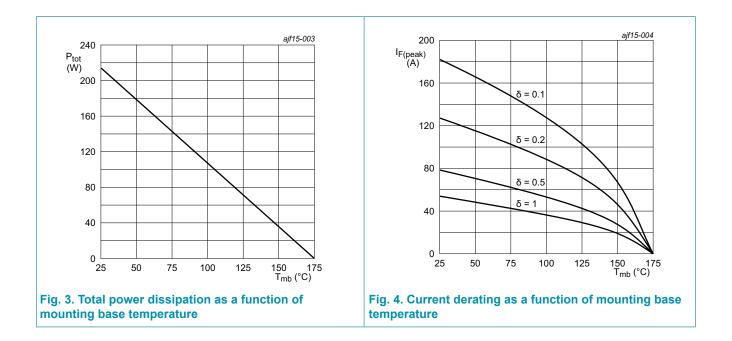


Fig. 1. Forward power dissipation as a function of average forward current; square waveform; typical values



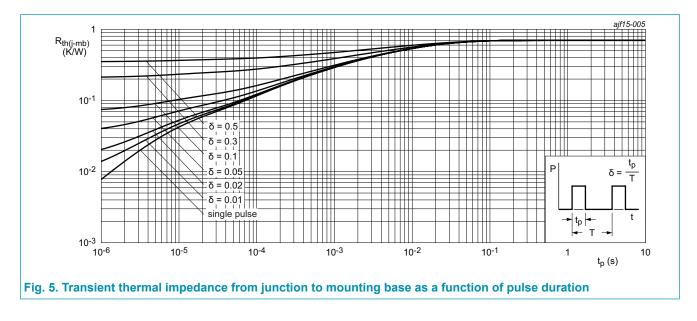


WNSC201200W Silicon Carbide Diode



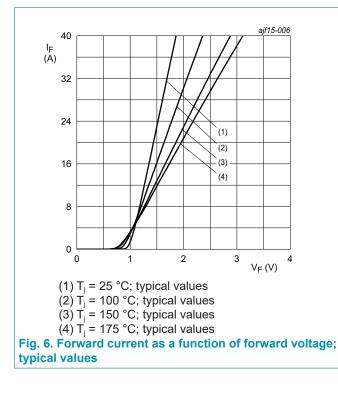
9. Thermal characteristics

Table 6. Th	ermal characteristics					
Symbol	Parameter	Conditions	Min	Тур	Max	Unit
$R_{th(j-mb)}$	thermal resistance from junction to mounting base	<u>Fig. 5</u>	-	-	0.7	K/W
$R_{th(j-a)}$	thermal resistance from junction to ambient free air	in free air	-	40	-	K/W



10. Characteristics

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
	aracteristics				indix	
V _F	forward current	I _F = 20 A; T _j = 25 °C; <u>Fig. 6</u>	-	1.4	1.6	V
		I _F = 20 A; T _j = 150 °C; <u>Fig. 6</u>	-	1.85	2.3	V
		I _F = 20 A; T _j = 175 °C; <u>Fig. 6</u>	-	2	2.6	V
I _R	reverse current	V _R = 1200 V; T _j = 25 °C; <u>Fig. 7</u>	-	-	200	μA
		V _R = 1200 V; T _j = 175 °C; <u>Fig. 7</u>	-	-	1	mA
Dynamic	characteristics	· · · · · ·				
Q _r	recovered charge	I _F = 20 A; V _R = 400 V; dI _F /dt = 500 A/μs; T _j = 25 °C; <u>Fig. 8</u>	-	52	-	nC
C _d	diode capacitance	f = 1 MHz; V _R = 1 V; T _j = 25 °C	-	1020	-	pF
		f = 1 MHz; V _R = 400 V; T _j = 25 °C	-	96	-	pF
		f = 1 MHz; V _R = 800 V; T _j = 25 °C	-	82	-	pF



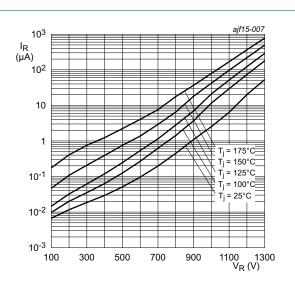
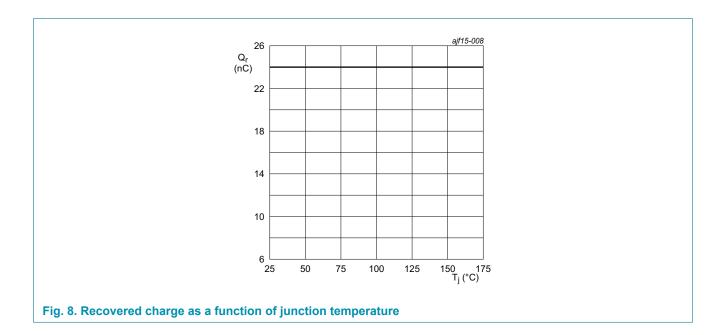


Fig. 7. Reverse leakage current as a function of reverse voltage; typical value

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11. Package outline

	-				e		- b1	E2	Q			- - C								D2
UNIT	A	A	Ъ	b 1	C	D	D1	\mathbf{D}_2	Е	E ₁	E ₂	E3	е	L	L	P ₂	p	Q	q	ø

WNSC201200W Product data sheet

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12. Legal information

Data sheet status

Document status [1][2]	Product status [3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

[1] Please consult the most recently issued document before initiating or completing a design.

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